Preferred Devices

Surface Mount Ultrafast Power Rectifiers

This series employs the state-of-the-art epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for high voltage, high frequency rectification, or as free wheeling and protection diodes, in surface mount applications where compact size and weight are critical to the system.

Features

- Small Compact Surface Mountable Package with J-Bend Leads
- Rectangular Package for Automated Handling
- Highly Stable Oxide Passivated Junction
- Low Forward Voltage Drop (0.71 to 1.05 Volts Max @ 3.0 A, T_J = 150°C)
- Pb-Free Packages are Available

Mechanical Characteristics

- Case: Epoxy, Molded
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight: 217 mg (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped in 16 mm Tape and Reel, 2500 units per reel
- Polarity: Notch in Plastic Body Indicates Cathode Lead
- Device Meets MSL1 Requirements
- ESD Ratings: Machine Model, C (> 400 V) Human Body Model, 3B (> 8000 V)

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ULTRAFAST RECTIFIERS 3.0 AMPERES 200-600 VOLTS



SMC CASE 403 PLASTIC

MARKING DIAGRAM



U3 = Specific Device Code

x = D, G, or J

A = Assembly Location

Y = Year

WW= Work Week

ORDERING INFORMATION

Device	Package	Shipping [†]	
MURS320T3	SMC	2500/Tape & Reel	
MURS320T3G	SMC (Pb-Free)	2500/Tape & Reel	
MURS340T3	SMC	2500/Tape & Reel	
MURS340T3G	SMC (Pb-Free)	2500/Tape & Reel	
MURS360T3	SMC	2500/Tape & Reel	
MURS360T3G	SMC (Pb-Free)	2500/Tape & Reel	

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

MAXIMUM RATINGS

Rating	Symbol	MURS320T3	MURS340T3	MURS360T3	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	200	400	600	V
Average Rectified Forward Current	I _{F(AV)}	3.0 @ T _L = 140°C 4.0 @ T _L = 130°C	3.0 @ T _L = 130°C 4.0 @ T _L = 115°C	3.0 @ T _L = 130°C 4.0 @ T _L = 115°C	Α
Non-Repetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I _{FSM}	75		A	
Operating Junction Temperature	TJ	- 65 to +175		°C	

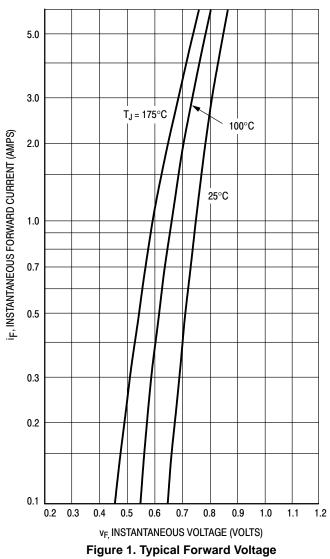
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Thermal Resistance, Junction-to-Lead	$R_{ heta JL}$	11			°C/W
ELECTRICAL CHARACTERISTICS					
$\label{eq:maximum Instantaneous Forward Voltage (Note 1)} $$ (i_F = 3.0 \text{ A}, T_J = 25^{\circ}\text{C})$ (i_F = 4.0 \text{ A}, T_J = 25^{\circ}\text{C})$ (i_F = 3.0 \text{ A}, T_J = 150^{\circ}\text{C})$$	V _F	0.875 0.89 0.71	1.25 1.28 1.05	1.25 1.28 1.05	V
Maximum Instantaneous Reverse Current (Note 1) (Rated dc Voltage, T _J = 25°C) (Rated dc Voltage, T _J = 150°C)	i _R	5.0 150	10 250	10 250	μΑ
Maximum Reverse Recovery Time $ (i_F = 1.0 \text{ A, di/dt} = 50 \text{ A/}\mu\text{s}) $ $ (i_F = 0.5 \text{ A, } i_R = 1.0 \text{ A, } I_{REC} \text{ to } 0.25 \text{ A}) $	t _{rr}	35 25	75 50	75 50	ns
Maximum Forward Recovery Time (i _F = 1.0 A, di/dt = 100 A/μs, Recovery to 1.0 V)	t _{fr}	25	50	50	ns

^{1.} Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

MURS320T3



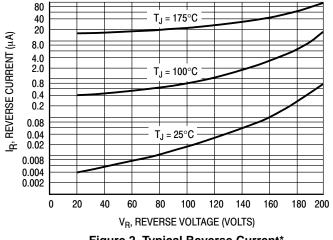


Figure 2. Typical Reverse Current*

* The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these same curves if V_R is sufficiently below rated V_R .

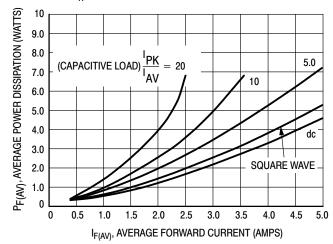


Figure 3. Power Dissipation

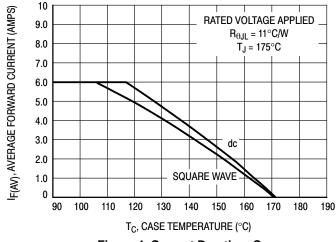


Figure 4. Current Derating, Case

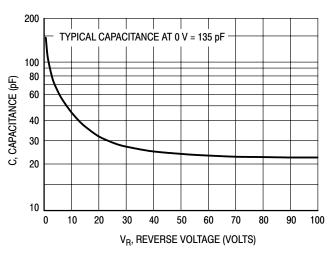


Figure 5. Typical Capacitance

MURS340T3, MURS360T3

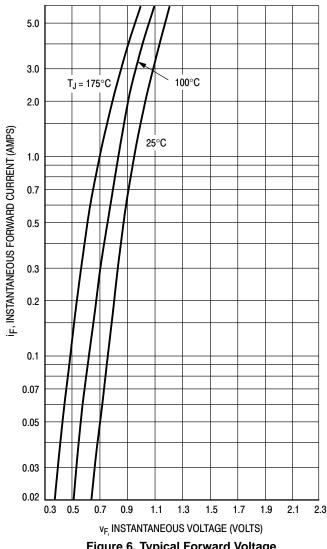


Figure 6. Typical Forward Voltage

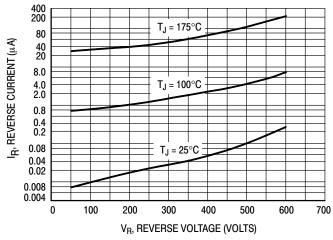


Figure 7. Typical Reverse Current*

* The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these same curves if V_R is sufficiently below rated V_R.

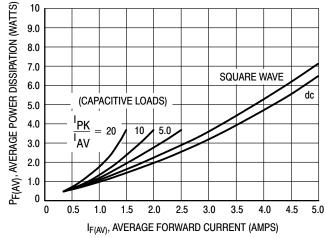


Figure 8. Power Dissipation

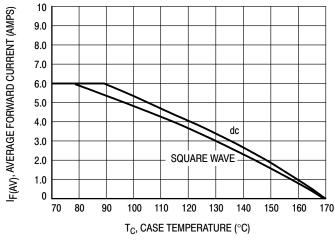


Figure 9. Current Derating, Case

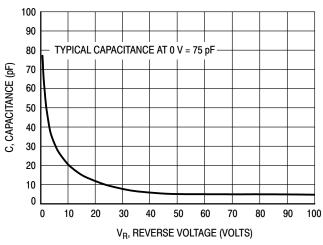
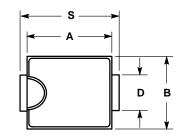
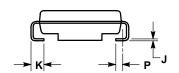


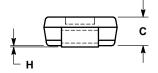
Figure 10. Typical Capacitance

PACKAGE DIMENSIONS

SMC PLASTIC PACKAGE CASE 403-03 ISSUE D



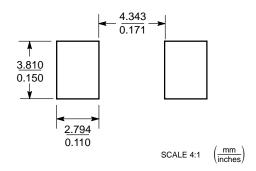




- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. D DIMENSION SHALL BE MEASURED WITHIN DIMENSION P.
 4. 403-01 THRU -02 OBSOLETE, NEW STANDARD 403-03.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.260	0.280	6.60	7.11
В	0.220	0.240	5.59	6.10
С	0.075	0.095	1.90	2.41
D	0.115	0.121	2.92	3.07
Н	0.0020	0.0060	0.051	0.152
J	0.006	0.012	0.15	0.30
K	0.030	0.050	0.76	1.27
P	0.020 REF		0.51 REF	
S	0.305	0.320	7.75	8.13

SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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